

MOS FIELD EFFECT TRANSISTOR 3SK224

RF AMPLIFIER FOR UHF TV TUNER N-CHANNEL SI DUAL GATE MOS FIELD-EFFECT TRANSISTOR 4 PINS MINI MOLD

FEATURES

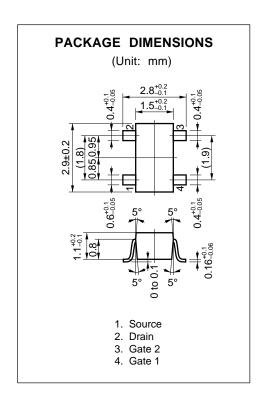
Low Noise Figure: NF = 1.8 dB TYP. (f = 900 MHz)
 High Power Gain: GPS = 17 dB TYP. (f = 900 MHz)

Suitable for use as RF amplifier in UHF TV tuner.
 Automatically Mounting: Embossed Type Taping
 Small Package: 4 Pins Mini Mold

ABSOLUTE MAXIMUM RATINGS (TA = 25 $^{\circ}$ C)

Drain to Source Voltage	VDSX	18	V
Gate1 to Source Voltage	V _{G1S}	±8 (±10)*1	V
Gate2 to Source Voltage	V _{G2} S	±8 (±10)*1	V
Gate1 to Drain Voltage	V_{G1D}	18	V
Gate2 to Drain Voltage	V_{G2D}	18	V
Drain Current	ΙD	25	mA
Total Power Dissipation	PD	200	mW
Channel Temperature	Tch	125	°C
Storage Temperature	Tstg	-55 to +125	°C

*1 R_L \geq 10 k Ω





ELECTRICAL CHARACTERISTICS (TA = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source Breakdown Voltage	BVDSX	18			V	$V_{G1S} = V_{G2S} = -2 \text{ V, ID} = 10 \mu\text{A}$
Drain Current	IDSX	0.5		15.0	mA	VDS = 6 V, VG2S = 3 V, VG1S = 0.5 V
Gate1 to Source Cutoff Voltage	VG1S(off)	-1.5		+0.5	V	$V_{DS} = 6 \text{ V}, V_{G2S} = 3 \text{ V}, I_{D} = 10 \mu A$
Gate2 to Source Cutoff Voltage	VG2S(off)	-1.0		+1.0	V	$V_{DS} = 6 \text{ V}, V_{G1S} = 3 \text{ V}, I_{D} = 10 \mu A$
Gate1 Reverse Current	I _{G1SS}			±20	nA	Vps = 0, Vg2s = 0, Vg1s = ±8 V
Gate2 Reverse Current	I _{G2SS}			±20	nA	Vps = 0, Vg1s = 0, Vg2s = ±8 V
Forward Transfer Admittance	yfs	18	22		mS	$V_{DS} = 5 \text{ V}, V_{G2S} = 4 \text{ V}, I_{D} = 10 \text{ mA}$ f = 1 kHz
Input Capacitance	Ciss	1.2	1.7	2.2	pF	V _{DS} = 6 V, V _{G2S} = 3 V, I _D = 10 mA f = 1 MHz
Output Capacitance	CDSS	0.5	0.9	1.2	pF	
Reverse Transfer Capacitance	Crss		0.015	0.025	pF	
Power Gain	Gps	15.0	17.0		dB	$V_{DS} = 6 \text{ V}, V_{G2S} = 3 \text{ V}, I_{D} = 10 \text{ mA}$ $f = 900 \text{ MHz}$
Noise Figure	NF		1.8	2.5	dB	

IDSX Classification

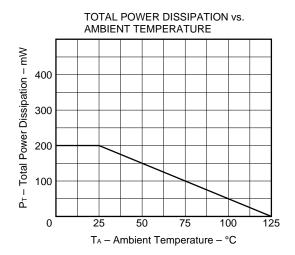
Class	U94/UID*	U95/UIE*		
Marking	U94	U95		
IDSX (mA)	0.5 to 7.0	5.0 to 15.0		

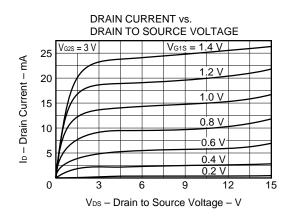
^{*} Old Specification/New Specification

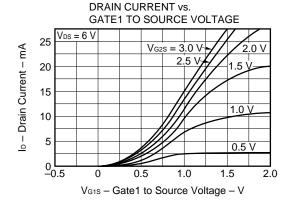
PRECAUTION: Avoid high static voltages or electric fields so that this device would not suffer from any damage due to those voltage or fields.

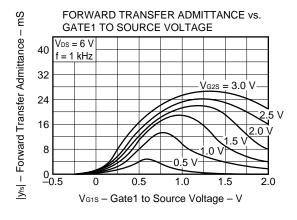
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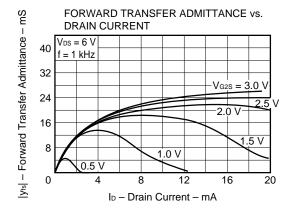
TYPICAL CHARACTERISTICS (TA = 25 $^{\circ}$ C)

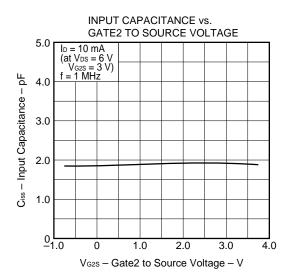


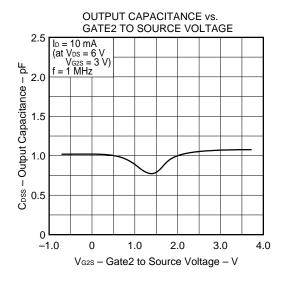


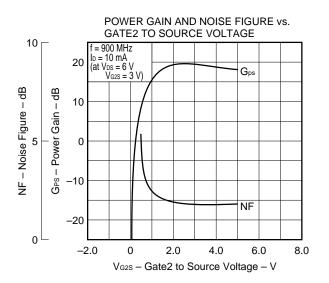




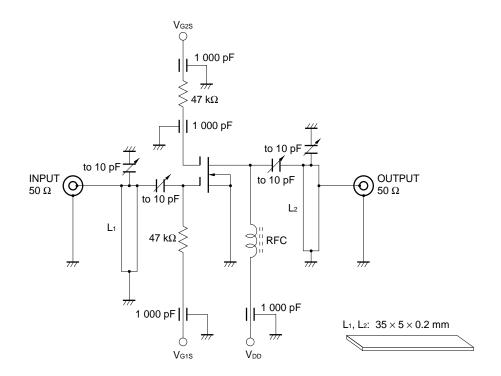








900 MHz GPS & NF TEST CIRCUIT



NEC 3SK224

[MEMO]

NEC 3SK224

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Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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Anti-radioactive design is not implemented in this product.

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